

KPESD5V0S1UL Ultra Low Capacitance ESD Protection Diode

DESCRIPTION

KPESD5V0S1UL a low-capacitance Transient Voltage Suppressor (TVS) designed to provide electrostatic discharge (ESD) protection for high-speed data interfaces. With typical capacitance of 0.4pF, is designed to .

protect parasitic-sensitive systems against over-voltage and over-current transient events. It complies with IEC 61000-4-2 (ESD), Level 4 (±15kV air, ±8kV contact discharge), IEC 61000-4-4 (electrical fast transient - EFT) (40A, 5/50 ns), very fast charged device model (CDM) ESD and cable discharge event (CDE), etc.

KPESD5V0S1UL ultra-small DFN1006 package.

The KPESD5V0S1UL device can protect one high-speed data line. It offers system designers flexibility to protect single data line where space is a premium concern. The combined features of low capacitance, ultra-small size and high ESD robustness make KPESD5V0S1UL ideal for high-speed data port and high-frequency line applications, such as cellular phones and HD visual devices.

FEATURES

☆Transient protection for high-speed data lines IEC 61000-4-2 (ESD) ±15kV (Air)

±8kV (Contact)

IEC 61000-4-4 (EFT) 40A (5/50 ns)

Cable Discharge Event (CDE)

- \diamond Package optimized for high-speed lines
- ♦Ultra-small package (1.0mm×0.6mm×0.5mm)
- \diamond Protects one data, control line
- ♦Low capacitance: 0.4pF (Typical)
- ♦Low leakage current
- ♦Low clamping voltage

MACHANICAL DATA

- ♦DFN1006 package
- ♦ Flammability Rating: UL 94V-0
- ♦Packaging: Tape and Reel
- \diamond High temperature soldering guaranted:260 °C/10s
- ♦Reel size: 7 inch

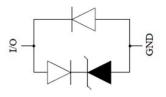
ORDERING INFORMATION

- ♦Device: KPESD5V0S1UL
- ♦Package: DFN1006
- ♦ Marking: 5L
- ♦Material: Halogen free
- ♦ Packing: Tape & Reel
- ♦Quantity per reel: 10,000pcs

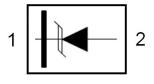
APPLICATIONS

- \diamond Serial ATA
- Desktops, Servers and Notebooks
- ♦ Cellular Phones
- ♦MDDI Ports
- ♦USB Data Line Protection
- ♦Display Ports
- ♦ Digital Visual Interfaces (DVI)

CIRCUIT DIAGRAM



PIN CONFIGURATION





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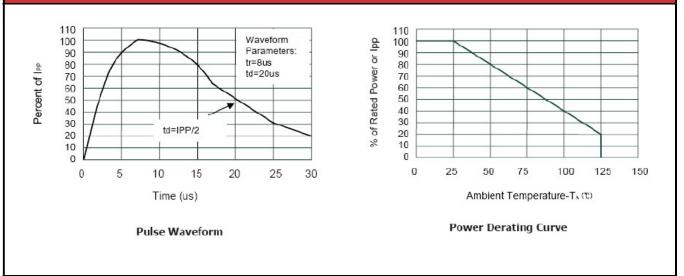
ABSOLUTE MAXIMUM RATING							
Symbol	Parameter	Value	Units				
V _{ESD}	ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	±20 ±20	kV				
P _{PP}	Peak Pulse Power (8/20µs)	60	W				
Т _{орт}	T _{OPT} Operating Temperature		°C				
T _{STG} Storage Temperature		-55~150	°C				

ELECTRICAL CHARACTERISTICS (Tamb=25°C)								
Symbol	Parameter	Test Condition	Min	Тур	Max	Units		
V _{RWM}	Reverse Working Voltage				5.0	V		
V _{BR}	Reverse Breakdown Voltage	I _T = 1mA	6.0			V		
I _R	Reverse Leakage Current	V _{RWM} = 5V			100	nA		
V _C	Clamping Voltage	I _{PP} = 1A, t _p = 8/20µs			10	V		
		I _{PP} = 4A, t _p = 8/20µs			15	V		
CJ	Junction Capacitance	V _R = 0V, f = 1MHz		0.4	0.5	pF		

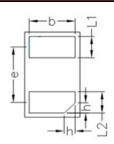


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ELECTRICAL CHARACTERISTICS CURVE



DFN1006 PACKAGE OUTLINE DIMENSIONS

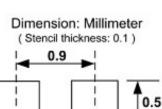


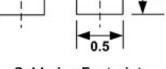






		ι	Jnit: mm		
	MIN	NOM	MAX		
D	0.55	0.60	0.65		
Ε	0.95	1.00	1.05		
L1	0.20	0.25	0.30		
_2	0.20	0.25	0.30		
b	0.45	0.50	0.55		
е	0.65BSC				
A	0.45	0.50	0.55		
h	0.07	0.12	0.17		





Soldering Footprint

单击下面可查看定价,库存,交付和生命周期等信息

>>KUU(永裕泰)